Silicon Power Transistors

The MJW21193 and MJW21194 utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

Features

- Total Harmonic Distortion Characterized
- High DC Current Gain
- Excellent Gain Linearity
- High SOA
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit		
Collector-Emitter Voltage	V _{CEO}	250	Vdc		
Collector-Base Voltage	V _{CBO}	400	Vdc		
Emitter-Base Voltage	V _{EBO}	5.0	Vdc		
Collector-Emitter Voltage - 1.5 V	V _{CEX}	400	Vdc		
Collector Current – Continuous	۱ _C	16	Adc		
Collector Current – Peak (Note 1)	I _{CM}	30	Adc		
Base Current – Continuous	Ι _Β	5.0	Adc		
Total Power Dissipation @ T _C = 25°C Derate Above 25°C	P _D	200 1.43	W W/°C		
Operating and Storage Junction Temperature Range	T _J , T _{stg}	– 65 to +150	°C		

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Pulse Test: Pulse Width = 5 μ s, Duty Cycle \leq 10%.

THERMAL CHARACTERISTICS

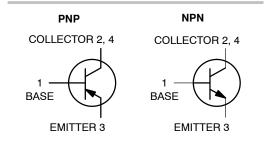
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.7	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	40	°C/W



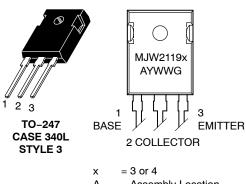
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16 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 250 VOLTS, 200 WATTS



MARKING DIAGRAM



A = Assembly Location

Y = Year

WW = Work Week

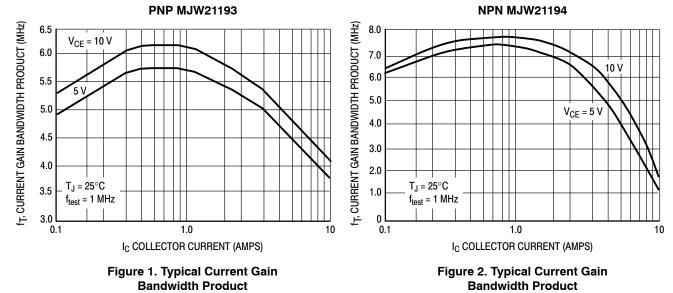
G = Pb-Free Package

ORDERING INFORMATION

Device	Package	Shipping
MJW21193G	TO-247 (Pb-Free)	30 Units/Rail
MJW21194G	TO–247 (Pb–Free)	30 Units/Rail

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
DFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage $(I_{C} = 100 \text{ mAdc}, I_{B} = 0)$	V _{CEO(sus)}	250	_	-	Vdc
Collector Cutoff Current ($V_{CE} = 200 \text{ Vdc}, I_B = 0$)	ICEO	-	_	100	μAdc
Emitter Cutoff Current ($V_{CE} = 5 \text{ Vdc}, I_C = 0$)	I _{EBO}	_	_	100	μAdc
Collector Cutoff Current (V _{CE} = 250 Vdc, V _{BE(off)} = 1.5 Vdc)	I _{CEX}	_	_	100	μAdc
SECOND BREAKDOWN					
Second Breakdown Collector Current with Base Forward $(V_{CE} = 50 \text{ Vdc}, t = 1 \text{ s (non-repetitive)})$ $(V_{CE} = 80 \text{ Vdc}, t = 1 \text{ s (non-repetitive)})$	Biased I _{S/b}	4.0 2.25			Adc
ON CHARACTERISTICS	<u>.</u>				
DC Current Gain (I _C = 8 Adc, V_{CE} = 5 Vdc) (I _C = 16 Adc, I _B = 5 Adc)	h _{FE}	20 8		80	
Base-Emitter On Voltage (I _C = 8 Adc, V _{CE} = 5 Vdc)	V _{BE(on)}	_	_	2.2	Vdc
Collector-Emitter Saturation Voltage ($I_C = 8 \text{ Adc}, I_B = 0.8 \text{ Adc}$) ($I_C = 16 \text{ Adc}, I_B = 3.2 \text{ Adc}$)	V _{CE(sat)}			1.4 4	Vdc
DYNAMIC CHARACTERISTICS					
Total Harmonic Distortion at the Output V _{RMS} = 28.3 V, f = 1 kHz, P _{LOAD} = 100 W _{RMS} h _F	E matched		0.8		%
(Matched pair h_{FE} = 50 @ 5 A/5 V) h_{F}		_	0.08	_	
Current Gain Bandwidth Product ($I_C = 1 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 1 \text{ MHz}$)	f _T	4	_	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	C _{ob}	-	-	500	pF



TYPICAL CHARACTERISTICS

1000

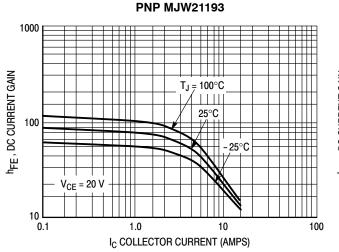
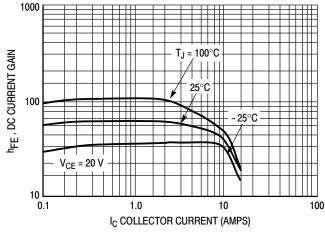


Figure 3. DC Current Gain, V_{CE} = 20 V



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Figure 4. DC Current Gain, V_{CE} = 20 V

NPN MJW21194

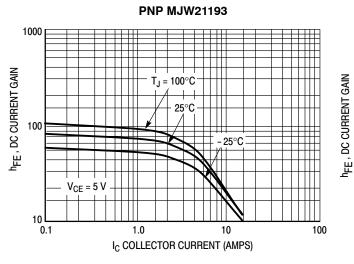
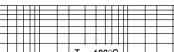
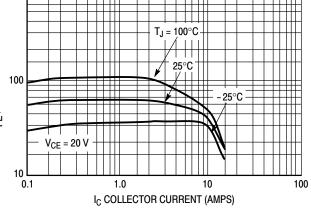


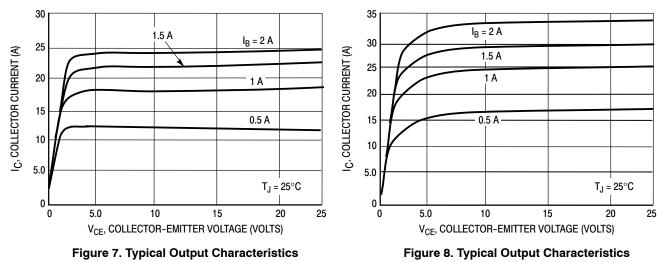
Figure 5. DC Current Gain, $V_{CE} = 5 V$







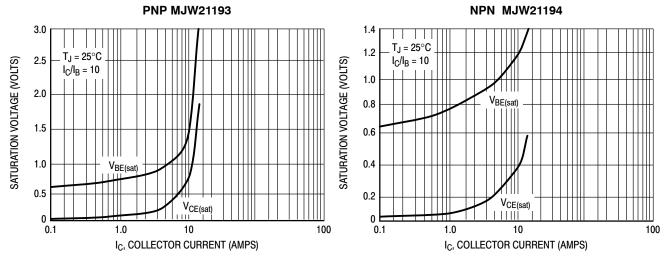
NPN MJW21194



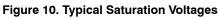
PNP MJW21193

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TYPICAL CHARACTERISTICS







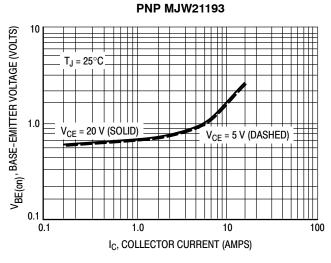


Figure 11. Typical Base–Emitter Voltage

1 Sec

10

100

10

1.0

0.1

1.0

I_C, COLLECTOR CURRENT (AMPS)

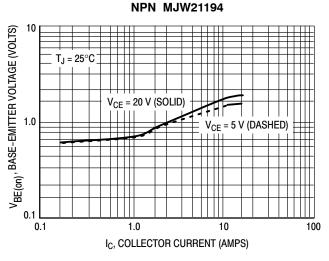
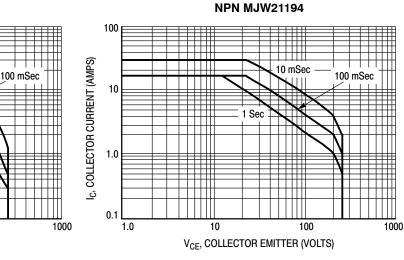


Figure 12. Typical Base-Emitter Voltage



PNP MJW21193

10 mSec

100



V_{CE}, COLLECTOR EMITTER (VOLTS)

Figure 14. Active Region Safe Operating Area

There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)} = 150^{\circ}$ C; T_{C} is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

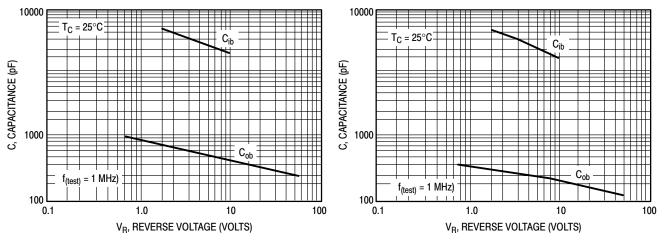


Figure 15. MJW21193 Typical Capacitance

Figure 16. MJW21194 Typical Capacitance

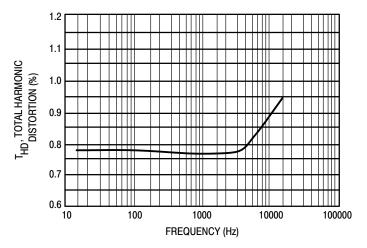


Figure 17. Typical Total Harmonic Distortion

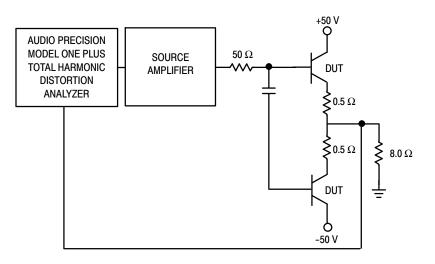
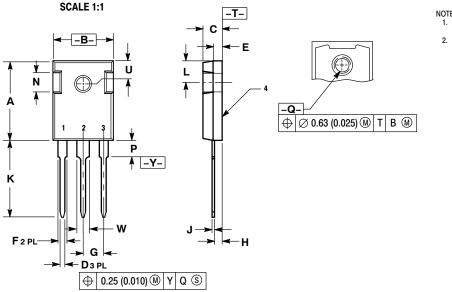


Figure 18. Total Harmonic Distortion Test Circuit

PACKAGE DIMENSIONS

TO-247 CASE 340L-02 ISSUE F



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	20.32	21.08	0.800	8.30
В	15.75	16.26	0.620	0.640
С	4.70	5.30	0.185	0.209
D	1.00	1.40	0.040	0.055
E	1.90	2.60	0.075	0.102
F	1.65	2.13	0.065	0.084
G	5.45 BSC		0.215 BSC	
H	1.50	2.49	0.059	0.098
J	0.40	0.80	0.016	0.031
K	19.81	20.83	0.780	0.820
L	5.40	6.20	0.212	0.244
N	4.32	5.49	0.170	0.216
P		4.50		0.177
Q	3.55	3.65	0.140	0.144
U	6.15 BSC		0.242	BSC
W	2.87	3.12	0.113	0.123

STYLE 3: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR

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